

Quad Precision, High Speed Operational Amplifier

OP467

00302-004

FEATURES

High slew rate: 170 V/µs Wide bandwidth: 28 MHz Fast settling time: <200 ns to 0.01% Low offset voltage: <500 µV Unity-gain stable Low voltage operation: ±5 V to ±15 V Low supply current: <10 mA Drives capacitive loads

APPLICATIONS

High speed image display drivers High frequency active filters Fast instrumentation amplifiers High speed detectors Integrators Photo diode preamps

GENERAL DESCRIPTION

The OP467 is a quad, high speed, precision operational amplifier. It offers the performance of a high speed op amp combined with the advantages of a precision op amp in a single package. The OP467 is an ideal choice for applications where, traditionally, more than one op amp was used to achieve this level of speed and precision.

The internal compensation of the OP467 ensures stable unitygain operation, and it can drive large capacitive loads without oscillation. With a gain bandwidth product of 28 MHz driving a 30 pF load, output slew rate is $170 \text{ V/}\mu\text{s}$, and settling time to 0.01% in less than 200 ns, the OP467 provides excellent dynamic accuracy in high speed data acquisition systems. The channel-to-channel separation is typically 60 dB at 10 MHz.

The dc performance of the OP467 includes less than 0.5 mV of offset, a voltage noise density below 6 nV/ \sqrt{Hz} , and a total supply current under 10 mA. The common-mode rejection ratio (CMRR) is typically 85 dB. The power supply rejection ratio (PSRR) is typically 107 dB. PSRR is maintained to better than 40 dB with input frequencies as high as 1 MHz. The low offset and drift plus high speed and low noise make the OP467 usable in applications such as high speed detectors and instrumentation.

The OP467 is specified for operation from \pm 5 V to \pm 15 V over the extended industrial temperature range (−40°C to +85°C) and is available in a 14-lead PDIP, a 14-lead CERDIP, a 16-lead SOIC, and a 20-terminal LCC.

Contact your local sales office for the MIL-STD-883 data sheet and availability.

Rev. *

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PIN CONFIGURATIONS

Figure 1. 14-Lead CERDIP (Y Suffix) and 14-Lead PDIP (P Suffix)

V+ Œ, Ŧ **OUT +IN –IN** $(\pmb{\ast})$ $\left(\blacklozenge\right)$ **V–**

Figure 4. Simplified Schematic

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REVISION HISTORY

8/09-Rev. G to Rev. H

$5/07$ —Rev. E to Rev. F

$3/04$ –Rev. D to Rev. E

$4/01$ -Rev. C to Rev. D

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS

@ $V_s = \pm 15.0$ V, T_A = 25°C, unless otherwise noted.

1 Long-term offset voltage drift is guaranteed by 1000 hrs. Life test performed on three independent wafer lots at 125°C, with an LTPD of 1.3.

@ $V_s = \pm 5.0$ V, $T_A = 25$ °C, unless otherwise noted.

Table 2.

WAFER TEST LIMITS¹

 ω V_s = ±15.0 V, T_A = 25°C, unless otherwise noted.

Table 3.

¹ Electrical tests and wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard

product dice. Consult sales to negotiate specifications based on dice lot qualifications through sample lot assembly and testing.
² Guaranteed by CMR test.

ABSOLUTE MAXIMUM RATINGS

Table 4.

¹ Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.

 2 For supply voltages less than ± 18 V, the absolute maximum input voltage is equal to the supply voltage.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

 θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 5.

¹ θ _{JA} is specified for the worst-case conditions, that is, θ _{JA} is specified for device in socket for CERDIP, PDIP, and LCC packages, and θ_{JA} is specified for device soldered in circuit board for the SOIC package.

DICE CHARACTERISTICS

Figure 5. 0.111 Inch \times 0.100 Inch DIE Size, 11,100 sq. mils, Substrate Connected to V+, 165 Transistors

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 9. Closed-Loop Output Impedance vs. Frequency

Figure 10. Gain Error vs. Frequency

Figure 11. Maximum V_{OUT} Swing vs. Frequency

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Figure 30. TC V_{os} Distribution

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Figure 35. Slew Rate vs. Temperature

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Figure 37. Supply Current vs. Supply Voltage

Figure 38. Input Bias Current vs. Temperature

Figure 39. Input Offset Current vs. Temperature

APPLICATIONS INFORMATION **OUTPUT SHORT-CIRCUIT PERFORMANCE**

To achieve a wide bandwidth and high slew rate, the OP467 output is not short-circuit protected. Shorting the output to ground or to the supplies may destroy the device.

For safe operation, the output load current should be limited so that the junction temperature does not exceed the absolute maximum junction temperature.

The maximum internal power dissipation can be calculated by

$$
P_D = \frac{T_J \max - T_A}{\theta_{JA}}
$$

where:

 T_J and T_A are junction and ambient temperatures, respectively. P_D is device internal power dissipation.

 θ_{IA} is the packaged device thermal resistance given in the data sheet.

UNUSED AMPLIFIERS

It is recommended that any unused amplifiers in the quad package be connected as a unity-gain follower with a 1 k Ω feedback resistor with noninverting input tied to the ground plain.

PCB LAYOUT CONSIDERATIONS

Satisfactory performance of a high speed op amp largely depends on a good PCB layout. To achieve the best dynamic performance, follow the high frequency layout technique.

GROUNDING

A good ground plain is essential to achieve the optimum performance in high speed applications. It can significantly reduce the undesirable effects of ground loops and IR drops by providing a low impedance reference point. Best results are obtained with a multilayer board design with one layer assigned to the ground plain. To maintain a continuous and low impedance ground, avoid running any traces on this layer.

POWER SUPPLY CONSIDERATIONS

In high frequency circuits, device lead length introduces an inductance in series with the circuit. This inductance, combined with stray capacitance, forms a high frequency resonance circuit. Poles generated by these circuits cause gain peaking and additional phase shift, reducing the phase margin of the op amp and leading to an unstable operation.

A practical solution to this problem is to reduce the resonance frequency low enough to take advantage of the power supply rejection of the amplifier. This is easily done by placing capacitors across the supply line and the ground plane as close as possible to the device pin. Because capacitors also have internal parasitic components, such as stray inductance, selecting the right capacitor is important. To be effective, they should have low impedance over the frequency range of interest. Tantalum capacitors are an excellent choice for their high capacitance/size ratio, but their effective series resistance (ESR) increases with frequency making them less effective.

On the other hand, ceramic chip capacitors have excellent ESR and effective series inductance (ESL) performance at higher frequencies, and because of their small size, they can be placed very close to the device pin, further reducing the stray inductance. Best results are achieved by using a combination of these two capacitors. A 5 μF to 10 μF tantalum parallel capacitor with a 0.1 μF ceramic chip capacitor is recommended. If additional isolation from high frequency resonances of the power supply is needed, a ferrite bead should be placed in series with the supply lines between the bypass capacitors and the power supply. Note that addition of the ferrite bead introduces a new pole and zero to the frequency response of the circuit and could cause unstable operation if it is not selected properly.

Figure 40. Recommended Power Supply Bypass

SIGNAL CONSIDERATIONS

Input and output traces need special attention to assure a minimum stray capacitance. Input nodes are very sensitive to capacitive reactance, particularly when connected to a high impedance circuit. Stray capacitance can inject undesirable signals from a noisy line into a high impedance input. Protect high impedance input traces by providing guard traces around them, which also improves the channel separation significantly.

Additionally, any stray capacitance in parallel with the input capacitance of the op amp generates a pole in the frequency response of the circuit. The additional phase shift caused by this pole reduces the gain margin of the circuit. If this pole is within the gain range of the op amp, it causes unstable performance. To reduce these undesirable effects, use the lowest impedance where possible. Lowering the impedance at this node places the poles at a higher frequency, far above the gain range of the amplifier. Stray capacitance on the PCB can be reduced by making the traces narrow and as short as possible. Further reduction can be realized by choosing a smaller pad size, increasing the spacing between the traces, and using PCB material with a low dielectric constant insulator (dielectric constant of some common insulators: air = 1, Teflon $^{\circ}$ = 2.2, and FR4 = 4.7, with air being an ideal insulator).

Removing segments of the ground plane directly under the input and output pads is recommended.

Outputs of high speed amplifiers are very sensitive to capacitive loads. A capacitive load introduces a pair of pole and zero to the frequency response of the circuit, reducing the phase margin, leading to unstable operation or oscillation.

Generally, it is good design practice to isolate the output of the amplifier from any capacitive load by placing a resistor between the output of the amplifier and the rest of the circuits. A series resistor of 10 Ω to 100 Ω is normally sufficient to isolate the output from a capacitive load.

The OP467 is internally compensated to provide stable operation and is capable of driving large capacitive loads without oscillation.

Sockets are not recommended because they increase the lead inductance/capacitance and reduce the power dissipation of the package by increasing the thermal resistance of the leads. If sockets must be used, use Teflon or pin sockets with the shortest possible leads.

PHASE REVERSAL

The OP467 is immune to phase reversal; its inputs can exceed the supply rails by a diode drop without any phase reversal.

SATURATION RECOVERY TIME

The OP467 has a fast and symmetrical recovery time from either rail. This feature is very useful in applications such as high speed instrumentation and measurement circuits, where the amplifier is frequently exposed to large signals that overload the amplifier.

Figure 43. Saturation Recovery Time, Negative Rail

HIGH SPEED INSTRUMENTATION AMPLIFIER

The OP467 performance lends itself to a variety of high speed applications, including high speed precision instrumentation amplifiers. [Figure 44](#page-13-1) represents a circuit commonly used for data acquisition, CCD imaging, and other high speed applications.

The circuit gain is set by R_G. A 2 k Ω resistor sets the circuit gain to 2; for unity gain, remove RG. For any other gain settings, use the following formula

```
G = 2/R<sub>G</sub> (Resistor Value is in kΩ)
```
 R_C is used for adjusting the dc common-mode rejection, and C_C is used for ac common-mode rejection adjustments.

Figure 44. A High Speed Instrumentation Amplifier

Figure 47. Settling Time Measurement Circuit

The circuit in [Figure 48](#page-14-1) is commonly used in medical imaging ultrasound receivers. The 30 MHz bandwidth is sufficient to accurately produce the 2 MHz center frequency, as the measured response shows in [Figure 49](#page-14-2). When the bandwidth of the op amp is too close to the center frequency of the filter, the internal phase shift of the amplifier causes excess phase shift at 2 MHz, which alters the response of the filter. In fact, if the chosen op amp has a bandwidth close to 2 MHz, the combined phase shift of the three op amps causes the loop to oscillate.

Careful consideration must be given to the layout of this circuit

If the phase shift introduced by the layout is large enough, it can alter the circuit performance, or worse, cause oscillation.

Figure 50. Quad DAC Unipolar Operation

FAST I-TO-V CONVERTER

The fast slew rate and fast settling time of the OP467 are well suited to the fast buffers and I-to-V converters used in a variety of applications. The circuit in [Figure 50](#page-15-1) is a unipolar quad DAC consisting of only two ICs. The current output of the DAC8408 is converted to a voltage by the OP467 configured as an I-to-V converter. This circuit is capable of settling to 0.1% within 200 ns. [Figure 51](#page-15-2) and [Figure 52](#page-15-3) show the full-scale settling time of the outputs. To obtain reliable circuit performance, keep the traces from the I_{OUT} of the DAC to the inverting inputs of the OP467 short to minimize parasitic capacitance.

Figure 51. Falling Edge Output Settling Time

OP467 SPICE MARCO-MODEL

. ENDS OP467

Figure 54. SPICE Macro-Model Output Stage

Figure 55. SPICE Macro-Model Input and Gain Stage

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OUTLINE DIMENSIONS

ORDERING GUIDE

1 Z = RoHS Compliant Part.

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